

BT155W-1200T

Rev.02 - 30 July 2019

SCR

**Product data sheet** 

### 1. General description

Planar passivated Silicon Controlled Rectifier in a TO247 plastic package intended for use in applications requiring very high inrush current capability and high thermal cycling performance.

### 2. Features and benefits

- High thermal cycling performance
- Planar passivated for voltage ruggedness and reliability
- High voltage capacity •
- Very high current surge capability

### 3. Applications

- Line rectifying 50/60 Hz •
- Softstart AC motor control
- DC Motor control •
- Power converter •
- AC power control •
- Lighting and temperature control • •
- Uninterruptible Power Supply (UPS)
- Solid State Relay (SSR)
- Traction battery charging

### 4. Quick reference data

Fable 1. Quick reference data							
Symbol	Parameter	Conditions	Values	Unit			
Absolute	Absolute maximum rating						
$V_{\text{DRM}}$	repetitive peak off-state voltage		1200	V			
$V_{\text{RRM}}$	repetitive peak reverse voltage		1200	V			
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>mb</sub> ≤ 131 °C; <u>Fig. 1</u> ; <u>Fig. 2; Fig. 3</u>	79	A			
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms; Fig. 4; Fig. 5	650	A			
		half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms	715	А			
T <sub>j</sub>	junction temperature		150	°C			

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Symbol	Parameter	Conditions			Тур	Max	Unit	
Static ch	Static characteristics							
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 7; Fig. 8</u>		-	-	50	mA	
Dynamic	Dynamic characteristics							
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 804 V; T <sub>j</sub> = 125 °C; R <sub>GK</sub> = 100 Ω; ( $V_{DM}$ = 67% of $V_{DRM}$ ); exponential waveform		1500	-	-	V/µs	

### 5. Pinning information . .

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode		
2	A	anode		A H K G
3	G	gate		sym037
mb	A	mounting base; connected to anode		

# 6. Ordering information

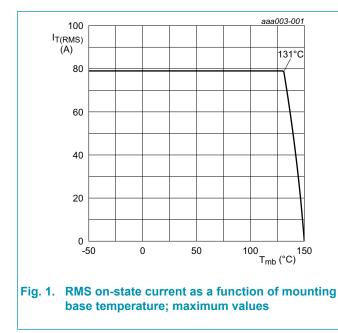
Table 3. Ordering information								
Type number	Package	Orderable part number	Packing	Small packing	Package	Package		
	Name		method	quantity	version	issue date		
BT155W-1200T	TO247	BT155W-1200TQ	Tube	30	TO247N	20-July-2016		

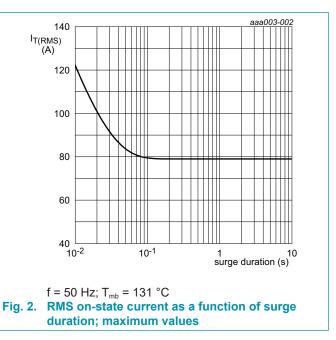
# 7. Limiting values

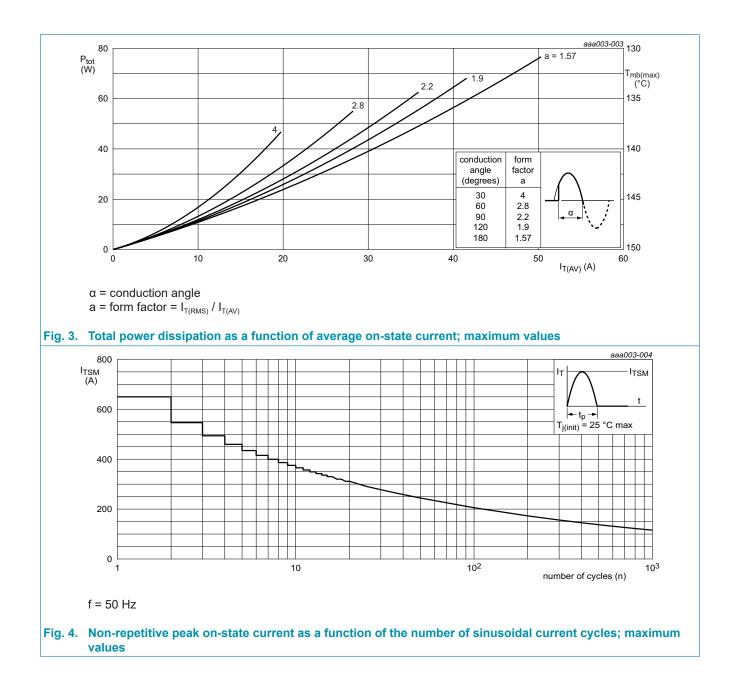
#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage		1200	V
$V_{\text{RRM}}$	repetitive peak reverse voltage		1200	V
$I_{T(AV)}$	average on-state current	half sine wave; T <sub>mb</sub> ≤ 131 °C	50	А
$\mathbf{I}_{\mathrm{T}(\mathrm{RMS})}$	RMS on-state current	half sine wave; T <sub>mb</sub> ≤ 131 °C; <u>Fig 1; Fig 2</u> ; <u>Fig 3</u>	79	A
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms; Fig 4; Fig 5	650	A
		half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms	715	А
l <sup>2</sup> t	l <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; sine-wave pulse	2113	A <sup>2</sup> s
dl <sub>⊤</sub> /dt	rate of rise of on-state current	I <sub>G</sub> = 200mA	150	A/µs
I <sub>GM</sub>	peak gate current		8	А
$V_{\text{RGM}}$	peak reverse gate voltage		5	V
$P_{GM}$	peak gate power		20	W
$P_{G(AV)}$	average gate power	over any 20 ms period	1	W
T <sub>stg</sub>	storage temperature		-40 to 150	°C
Tj	junction temperature		150	°C







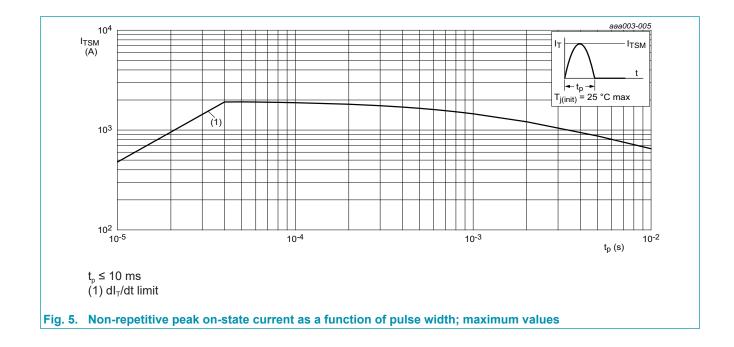
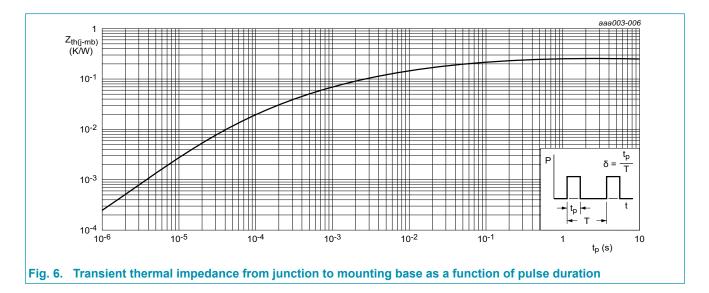


Table 5.	Thermal	&	Mechanical	characteristics
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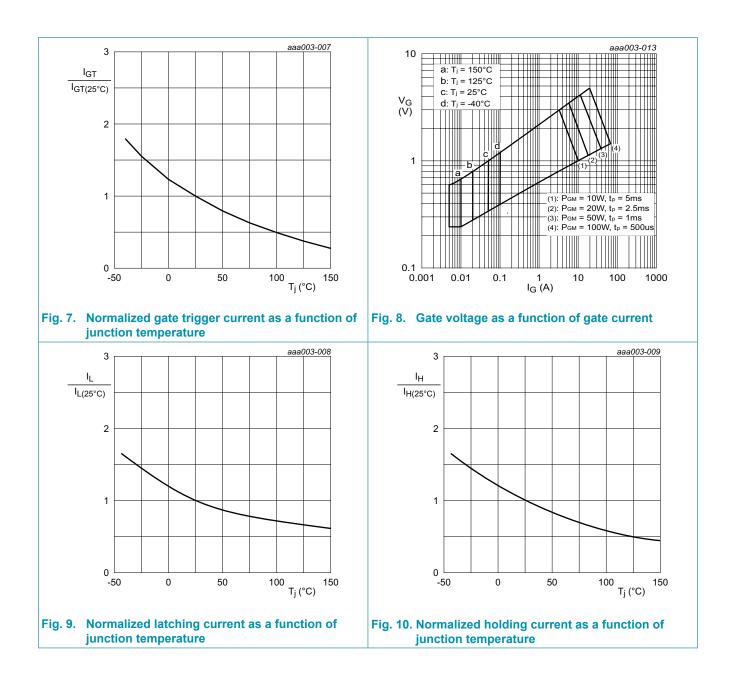
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	<u>Fig 6</u>	-	-	0.25	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	50	-	K/W
	Mounting torque	M3 screw mounting	0.55	-	0.8	Nm

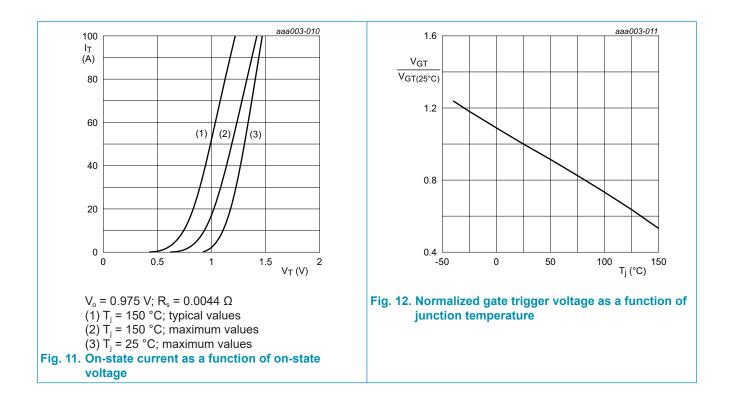
Note: It is recommended that a metal washer is inserted between screw head and mounting tab. Do not use self-tapping screws.



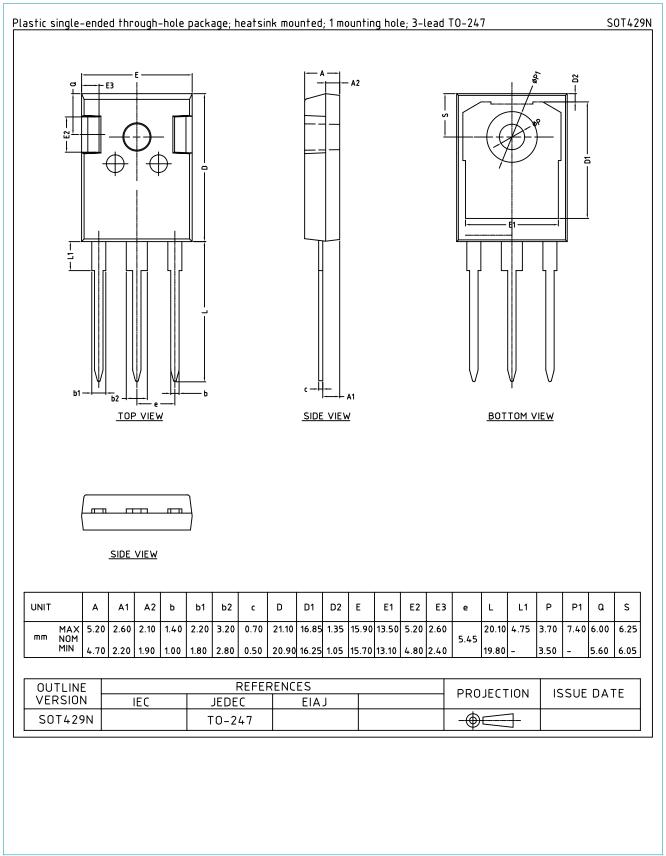
# 9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics	·				
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; Fig. 7; Fig. 8	-	-	50	mA
I <sub>L</sub>	latching current	$V_{\rm D}$ = 12 V; I <sub>G</sub> = 0.1 A; T <sub>j</sub> = 25 °C; Fig. 9	-	-	300	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	-	200	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 50 A; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>	-	-	1.3	V
		I <sub>T</sub> = 90 A; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>	-	-	1.5	V
V <sub>GT</sub> gate trigger voltage		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 25 \text{ °C};$ Fig. 12	-	0.7	1	V
		V <sub>D</sub> = 800 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 125 °C	0.25	0.4	-	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 1200 V; T <sub>j</sub> = 125 °C	-	-	3	mA
I <sub>R</sub>	reverse current	V <sub>D</sub> = 1200 V; T <sub>j</sub> = 125 °C	-	-	3	mA
Dynamic	characteristics	· · · · ·				
dV <sub>D</sub> /dt rate of rise of off-state voltage			1500	-	-	V/µs
		$V_{DM}$ = 804 V; T <sub>j</sub> = 150 °C; R <sub>GK</sub> = 100 Ω; ( $V_{DM}$ = 67% of $V_{DRM}$ ); exponential waveform	1000	-	-	V/µs
t <sub>gt</sub>	gate-controlled turn-on time	$ \begin{array}{l} {I_{\text{TM}}} = 40 \text{ A};  V_{\text{D}} = 800  \text{V};  {I_{\text{G}}} = 0.1  \text{A};  \text{d} {I_{\text{G}}} \text{/} \\ \text{d} t = 5  \text{A} \text{/} \mu \text{s};  \text{T}_{\text{j}} = 25 ^{\circ} \text{C} \end{array} $	-	2	-	μs
t <sub>q</sub>	commutated turn-off time		-	150	-	μs





# 10. Package outline



# 11. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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